

SMALL SIGNAL SCHOTTKY DIODE

Table 1: Main Product Characteristics

$I_{F(AV)}$	0.1 A
V_{RRM}	30 V
T_j	150°C
$V_F(\text{max})$	0.33 and 0.40 V

FEATURES AND BENEFITS

- Very small conduction losses
- Negligible switching losses
- Low forward voltage drop
- Surface mount device

DESCRIPTION

General purpose metal to silicon diodes featuring very low turn-on voltage and fast switching.

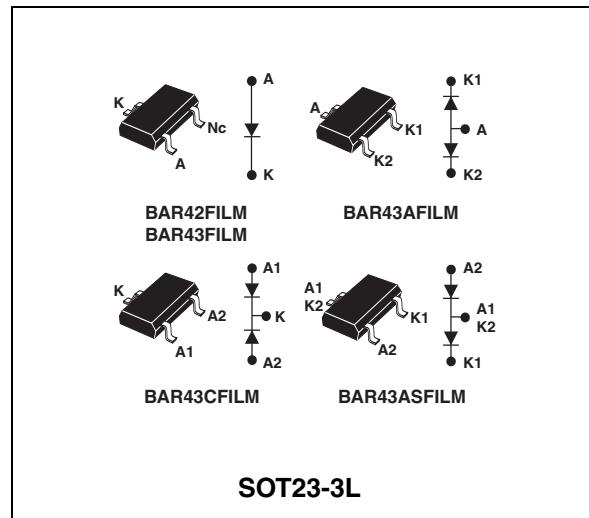


Table 2: Order Codes

Part Number	Marking
BAR42FILM	D94
BAR43FILM	D95
BAR43AFILM	DB1
BAR43CFILM	DB2
BAR43SFILM	DA5

Table 3: Absolute Ratings (limiting values)

Symbol	Parameter		Value	Unit
V_{RRM}	Repetitive peak reverse voltage		30	V
$I_{F(AV)}$	Continuous forward current		0.1	A
I_{FSM}	Surge non repetitive forward current	$t_p = 10\text{ms sinusoidal}$	0.75	A
P_{tot}	Power dissipation (note 1)	$T_{amb} = 25^\circ\text{C}$	250	mW
T_{stg}	Maximum storage temperature range		-65 to + 150	°C
T_j	Maximum operating junction temperature *		150	°C
T_L	Maximum temperature for soldering during 10s		260	°C

Note 1: for double diodes, P_{tot} is the total dissipation of both diodes.

* : $\frac{dP_{tot}}{dT_j} > \frac{1}{R_{th}(j-a)}$ thermal runaway condition for a diode on its own heatsink

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Table 4: Thermal Resistance

Symbol	Parameter	Value	Unit
R _{th(j-a)}	Junction to ambient (*)	500	°C/W

(*) Mounted on epoxy board with recommended pad layout.

Table 5: Static Electrical Characteristics

Symbol	Parameter	Tests conditions		Min.	Typ	Max.	Unit
V _{BR}	Breakdown voltage	T _j = 25°C	I _R = 100µA	30			V
I _R *	Reverse leakage current	T _j = 25°C	V _R = V _{RRM}			500	nA
		T _j = 100°C				100	µA
V _F **	Forward voltage drop	T _j = 25°C	BAR42	I _F = 10mA		0.35	0.40
				I _F = 50mA		0.50	0.65
			BAR43	I _F = 2mA	0.26		0.33
				I _F = 15mA			0.45
			ALL	I _F = 100mA			1

Pulse test:
* tp = 5 ms, $\delta < 2\%$
** tp = 380 µs, $\delta < 2\%$

Table 6: Dynamic Characteristics (T_j = 25°C)

Symbol	Parameter	Tests conditions		Min.	Typ.	Max.	Unit
C	Junction capacitance	T _j = 25°C	V _R = 1V	F = 1 MHz		7	pF
t _{rr}	Reverse recovery time	I _F = 10 mA	I _R = 10 mA			5	ns
η	Detection efficiency	C _L = 300 pF	F = 45 MHz		80		%
		T _j = 25°C	V _i = 2 V	R _L = 50 Ω			

Figure 1: Forward voltage drop versus forward current (typical values, low level)

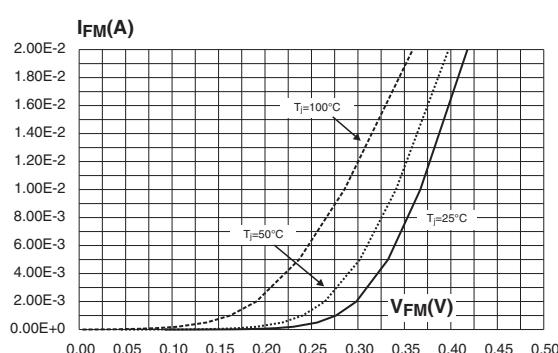
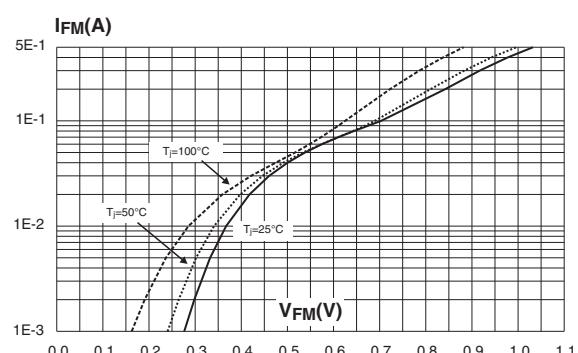
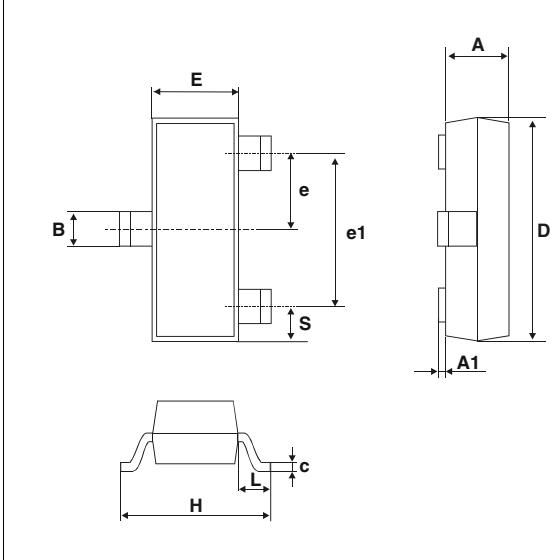


Figure 2: Forward voltage drop versus forward current (typical values, high level)



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Figure 8: SOT23-3L Package Mechanical Data



REF.	DIMENSIONS			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	0.89	1.4	0.035	0.055
A1	0	0.1	0	0.004
B	0.3	0.51	0.012	0.02
c	0.085	0.18	0.003	0.007
D	2.75	3.04	0.108	0.12
e	0.85	1.05	0.033	0.041
e1	1.7	2.1	0.067	0.083
E	1.2	1.6	0.047	0.063
H	2.1	2.75	0.083	0.108
L	0.6 typ.		0.024 typ.	
S	0.35	0.65	0.014	0.026

Figure 9: Foot Print Dimensions (in millimeters)

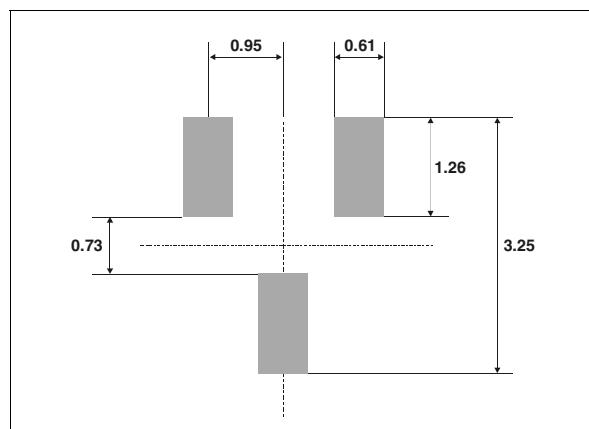


Table 7: Ordering Information

Ordering type	Marking	Package	Weight	Base qty	Delivery mode
BAR42FILM	D94	SOT23-3L	0.01 g	3000	Tape & reel
BAR43FILM	D95				
BAR43AFILM	DB1				
BAR43CFILM	DB2				
BAR43SFILM	DA5				

- Epoxy meets UL94, V0

Table 8: Revision History

Date	Revision	Description of Changes
Aug-2001	2B	Last update.
16-Apr-2005	3	Layout update. No content change.